

2D crystal based Heterostructures: from Superlattices to Devices

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The isolation of various two-dimensional (2D) materials, and the possibility to combine them in vertical stacks, has created a new paradigm in materials science: heterostructures based on 2D crystals. Such a concept can be used to focus on particular phenomena or for specific applications.

In this talk I will show that layering sheets of graphene and hexagonal boron nitride (hBN), molybdenum disulfide (MoS_2), or tungsten disulfide (WS_2) allow operation of tunnelling transistors [1,2] and efficient flexible photovoltaic devices with external quantum efficiency of above 30% [3]. Furthermore, I will show that graphene placed on hexagonal-Boron Nitride (h-BN) experiences a superlattice potential, which leads to a strong reconstruction of graphene's electronic spectrum [4,5]. Raman spectroscopy is found to allow high-throughput and non-destructive identification of graphene/hBN superlattices [6], making this technique a fundamental tool in the fabrication of superlattice based-devices.

In the last part of this talk I will show that heterostructures can also be assembled from chemically exfoliated 2D crystals [7], allowing for low-cost and scalable methods to be used in heterostructures fabrication [8].

References

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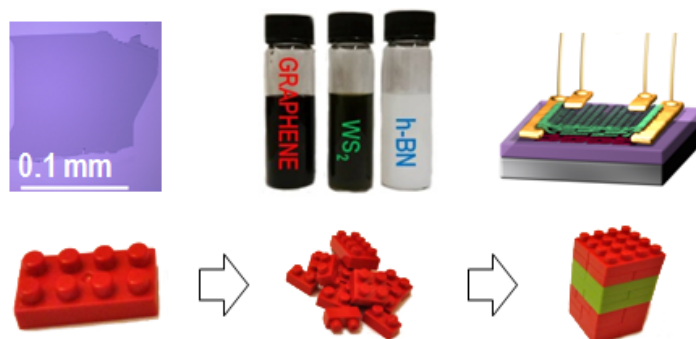


Figure 1: Heterostructure based photo-detectors can be assembled from 2D crystals inks.